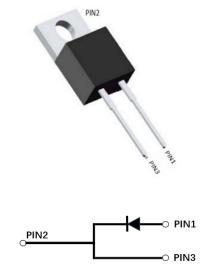


# YJD112005PG1Q



V <sub>RRM</sub>	1200V
I <sub>F (135°C)</sub>	8.4A
Q <sub>c</sub>	27nC



#### Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

#### **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

#### **Mechanical Data**

- Package: TO-220AC
- Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

## **■Maximum Ratings (** $T_c$ **=**25°C Unless otherwise specified )

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112005PG1
Reverse voltage (Repetitive peak) @ T <sub>j</sub> =25°C	V <sub>RRM</sub>	V	1200
Reverse voltage (Surge peak) @ T <sub>j</sub> =25°C	V <sub>RSM</sub>	V	1200
Reverse voltage (DC) @ T <sub>j</sub> =25°C	V <sub>DC</sub>	V	1200
Continuous forward current @ T <sub>c</sub> =25°C			17.3
Continuous forward current @ T <sub>c</sub> =135°C	I <sub>F</sub>	А	8.4
Continuous forward current @ T <sub>c</sub> =158°C			5
Non-repetitive peak forward surge current @ $T_c$ =25°C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	50
Power Dissipation@ T <sub>c</sub> =25°C		W	95
Power Dissipation@ T <sub>c</sub> =110°C	P <sub>TOT</sub>		41
i²t Value@ T <sub>c</sub> =25°C ,tp=10ms	∫ i²dt	A <sup>2</sup> S	12.5
Operating junction and Storage temperature range	T <sub>j</sub> ,T <sub>stg</sub>	°C	-55 to +175



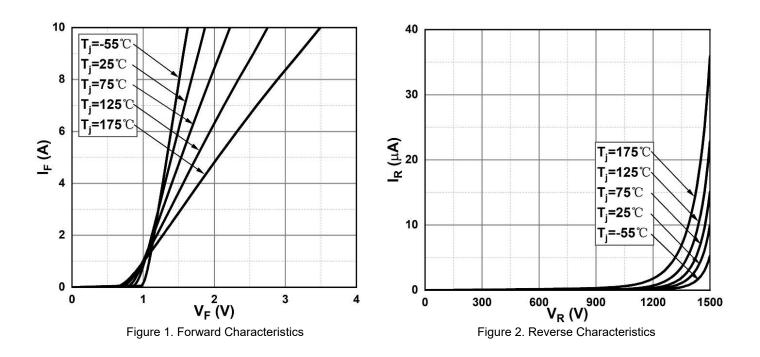
#### Electrical Characteristics

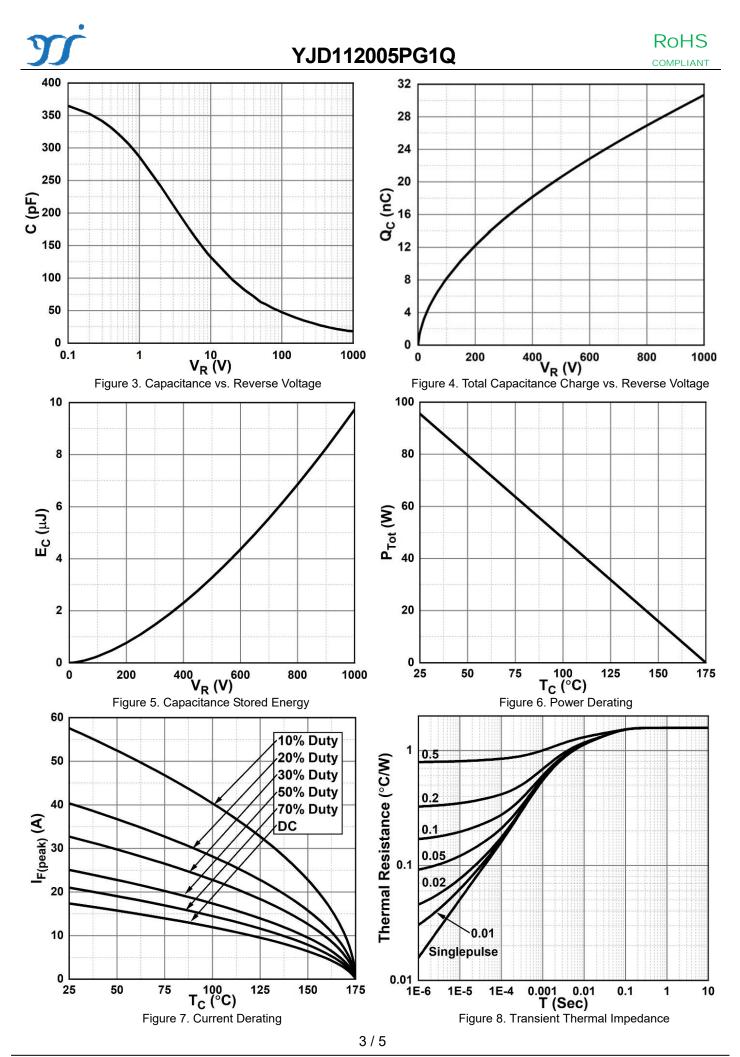
PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
E		v	I <sub>F</sub> =5A, T <sub>j</sub> =25°C	1.41	1.6
Forward voltage drop	V <sub>F</sub>		I <sub>F</sub> =5A, T <sub>j</sub> =175°C	2.1	-
	I <sub>R</sub>		V <sub>R</sub> =1200V, T <sub>j</sub> =25°C	0.5	16
Reverse leakage current		μA	V <sub>R</sub> =1200V, T <sub>j</sub> =175°C	8	-
Total capacitive charge	Qc	nC	$V_R$ =800V, T <sub>j</sub> =25°C , $Q_C$ = $\int_0^{VR}$ C(V)dV	27	-
Total capacitance		pF	V <sub>R</sub> =0V, f=1MHZ	377	-
	С		V <sub>R</sub> =400V, f=1MHZ	25	-
			V <sub>R</sub> =800V, f=1MHZ	19	-
Capacitance Stored Energy	Ec	μJ	V <sub>R</sub> =800V	6.8	-

#### ■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C W	1.57

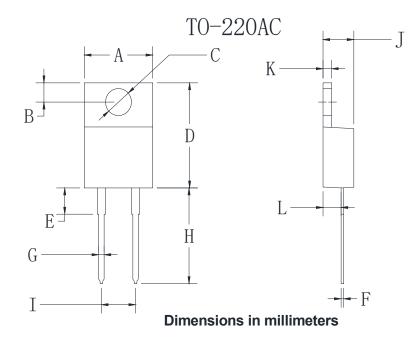
## ■Typical Characteristics







# Outline Dimensions



	TO 222 A C			
TO-220AC				
Dim	Min	Max		
А	9.95	10.35		
В	2.55	2.95		
С	3.75	4.05		
D	14.95	15.25		
E	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.3	13.9		
Ι	4.86	5.26		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		

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